



(19)

Europäisches Patentamt
European Patent Office
Office européen des brevets



(11)

EP 0 803 927 A2

(12)

EUROPEAN PATENT APPLICATION

(43) Date of publication:
29.10.1997 Bulletin 1997/44

(51) Int. Cl. 6: **H01P 1/00**(21) Application number: **97302840.0**(22) Date of filing: **25.04.1997**

(84) Designated Contracting States:
DE FI FR GB

(72) Inventor: **Wada, Yasuhiro**
Takatsuki-shi, Osaka (JP)

(30) Priority: **26.04.1996 JP 107243/96**

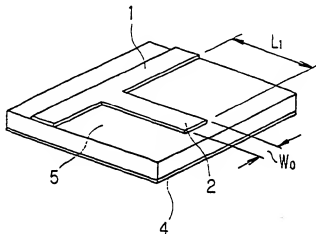
(74) Representative: **Brown, Kenneth Richard et al**
R.G.C. Jenkins & Co.
26 Caxton Street
London SW1H 0RJ (GB)

(71) Applicant: **SHARP KABUSHIKI KAISHA**
Osaka-shi Osaka 545 (JP)

(54) Attenuating filter for a DBS tuner for satellite broadcasting receivers

(57) A DBS tuner for satellite broadcasting receivers, includes an attenuating filter (trap circuitry) com-

posed of a microstrip line having an open-ended load terminal which projects from the RF signal line or the power supply line.

FIG. 6A

Description

BACKGROUND OF THE INVENTION

(1) Field of the Invention

The present invention relates to a circuit configuration of a DBS tuner for satellite broadcasting receivers, and in particular relates to a DBS tuner for satellite broadcasting receivers wherein an attenuating filter (trapping circuit) using a microstrip line is provided on the printed circuit board.

(2) Description of the Prior Art

In a general satellite broadcasting receiving system, ground waves of the 12 GHz band are collected first by a BS antenna, and a BS converter converts it in frequency into a high-frequency signal of the 1 GHz band (900 to 2150 MHz). This is introduced to a DBS tuner where a desired signal channel is selected from the 1 GHz band signals sent from the BS converter so that the selected signal is converted into the intermediate frequency signal (402.73 MHz). Here, DBS represents direct broadcasting satellite, and means a system which directly receives broadcast signals from communications satellites.

Fig. 1 shows an example of a circuit block diagram of a conventional DBS tuner for satellite broadcasting receivers. The double line connecting different circuit portions represents the RF signal line; the single line represents the power line.

In a conventional DBS tuner, an input signal of the 1 GHz band applied to an input terminal 51 is made to pass through a wideband amplifier or RF circuit portion 52, an attenuator 53, a tracking filter 54 to be supplied to a mixer 55. The locally generated signal from a local oscillator circuit portion 56 is inputted to a PLL (phase-locked loop) 58 through a high-pass filter 57. PLL 58 operates so that the locally generated signal from local oscillator circuit portion 56 is phase-locked. The locally generated signal locked in phase is inputted to mixer 55 where it is converted into the intermediate frequency signal (IF signal). This IF signal is applied to an IF circuit portion 60 and inputted to a demodulating portion 61. A reference numeral 62 designates a power input terminal which is connected to RF circuit portion 52, mixer 55, PLL 58, local oscillator circuit portion 56, IF circuit portion 60 and demodulating portion 61. The frequency of the IF signal output in this case is 402.73 MHz. RF circuit portion 52 and IF circuit portion 60 process a modulated signal. Demodulator 61 detects and demodulates the modulated signal to output it as a detected signal. The RF circuit portion operates so as to adjust the level of the attenuator, which is a circuit provided to keep the signal at a constant level free from distortion even if the level of the RF input signal level varies.

The signal lines connecting various portions, specifically, input terminal 51, RF circuit portion 52, attenuator 53, tracking filter 54, mixer 55, PLL 58, local oscillator circuit portion 56, IF circuit portion 60, power terminal 62 and demodulator 61, is composed of copper foil leads provided on the printed circuit board as shown in Fig. 4. Designated at 65 in Fig. 4 is a dielectric support of the printed circuit board, 66 a signal line and 67 a copper foil layer formed on the underside of the printed circuit board. Signal line 66 is provided in the form of a simple strip-like conductor.

The circuit configuration of the conventional DBS tuner for satellite broadcasting receivers, has a means for preventing leakage of the locally generated signal (including fundamental harmonic, second order harmonic, third order harmonic) from the input terminal. This means is provided as a low-pass filter connected to GND 70 and composed of a chip capacitor 68 and a strip line 69 as shown in Fig. 2, for example, inside RF circuit portion 52 or tracking filter 54 such as $\lambda/2$ type band-pass filter (B.P.F.) or $\lambda/4$ type B.P.F., etc., so as to damp the aforementioned signal.

Further, to prevent leakage of the locally generated signal (including fundamental harmonic, second order harmonic, third order harmonic) from the power supply terminal, a bypass capacitor 71 as shown in Fig. 3 is connected to GND 70 to damp the signal.

In the conventional DBS tuner for satellite broadcasting receivers, in order to prevent entrance of the second and third harmonic components of the locally generated signal from local oscillator circuit 56 into PLL circuit 58, the aforementioned bypass capacitor, for example, is connected between the locally generated signal transmission line and the GND, as shown in Fig. 1, so as to damp the higher harmonic components.

As a technique for preventing entrance of the higher harmonic components of the VCO oscillating signal into the demodulator, the aforementioned bypass capacitor is connected between a RFAGC line 59 and GND (earth) to damp the higher harmonics. RFAGC line 59 is a high-frequency line which connects attenuator 53 with demodulator 61.

Concerning prevention of leakage of the locally generated signal from the high-frequency input terminal, it is possible in the prior art to sufficiently attenuate the fundamental wave, but it is impossible to damp the higher frequency ranges, i.e., the second and third order harmonics, causing leakage from the high-frequency input terminal. This can be attributed to the increase in the inductance component of the leads and electrodes of the chip capacitor constituting the filter, accompanied by the augmentation of the frequencies of the second and third order harmonics. It is also

attributed to a change in the inductance components of the strip lines depending upon frequencies. The leakage of the locally generated signal from the high-frequency input terminal will cause interference in the reception of other DBS tuners connected to the common cable and other appliances.

Here, the fundamental wave of the locally generated signal of DBS tuners for satellite broadcasting receivers is within 1300 MHz to 2550 MHz. The frequency of its second order harmonic falls within $(1300 \text{ MHz to } 2550 \text{ MHz}) \times 2$ and the frequency of its third order harmonic falls within $(1300 \text{ MHz to } 2550 \text{ MHz}) \times 3$.

The frequency of the fundamental wave of the VCO oscillating signal is 402.75 MHz. The frequency of its second order harmonic is $402.75 \text{ MHz} \times 2$, and the frequency of its third order harmonic is $402.75 \text{ MHz} \times 3$.

Concerning the protection against interference caused by the second and third order harmonics of the locally generated signal inputted from the local oscillator circuit to the PLL circuit portion, in the prior art, since the self-resonance frequency (about 1 GHz) of the bypass capacitor (of, e.g., about 1000 pF) is lower than the frequency of the locally generated signal (about 1300 MHz to 2550 MHz), the inductance of the leads and electrodes of the chip capacitor is consequently large so that it is impossible to sufficiently attenuate the signal component to the GND (earth).

Thus, various causes give rise to a problem that the harmonic components enter the PLL circuit, resultantly, the conventional configuration suffers from malfunction of channel section in the PLL circuit.

Concerning the protection against the leakage of the locally generated signal (including fundamental harmonic, second order harmonic, third order harmonic) from the power supply terminal, in the prior art, the leakage of the aforementioned signal causes unwanted radiation from the appliance incorporating the DBS tuner.

Concerning the protection against interference caused by the VCO oscillating signal harmonic components from the demodulating circuit portion through the RFAGC line, the prior art technology cannot sufficiently attenuate them because of the augmentation of the inductance component in the aforementioned bypass capacitor. Therefore, if the receiver receives a RF signal having a frequency (about 1.2 GHz, 1.6 GHz, 2.0 GHz) which is close to the VCO oscillating signal harmonics, the aforementioned harmonic components cause beats if it returns to the RF signal line.

SUMMARY OF THE INVENTION

It is therefore an object of the present invention to provide a DBS tuner for satellite broadcasting receivers wherein an attenuating filter (trap circuitry) for preventing leakage of the locally generated signal (containing its higher harmonics) or leakage of the VCO oscillating signal (containing its higher harmonics) is provided.

The present invention has been devised in order to attain the above object, and is configured as follows:

In accordance with the first aspect of the invention, a DBS tuner for satellite broadcasting receivers, comprises an attenuating filter composed of a microstrip line having an open-ended load terminal which projects from the RF signal line or the power supply line.

Next, the second aspect of the invention resides in the DBS tuner for satellite broadcasting receiver having the above first feature, wherein the attenuating filter is configured with a plurality of microstrip lines different in length having a plurality of open-ended load terminals.

The third aspect of the invention resides in the DBS tuner for satellite broadcasting receiver having the above first feature, wherein the attenuating filter is configured so that a GND pattern is formed almost entirely on the dielectric substrate on the side opposite to the surface where the microstrip lines are formed.

The fourth aspect of the invention resides in the DBS tuner for satellite broadcasting receiver having the above first feature, wherein the attenuating filter is provided in the RF line which connects the input terminal to the DBS tuner for broadcasting receivers with the local oscillator circuit portion.

The fifth aspect of the invention resides in the DBS tuner for satellite broadcasting receivers having the above second feature, wherein the attenuating filter is provided in the RF line which connects the input terminal to the DBS tuner for broadcasting receivers with the local oscillator circuit portion.

The sixth aspect of the invention resides in the DBS tuner for satellite broadcasting receivers having the above first feature, wherein the attenuating filter is provided in the power supply line inside the DBS tuner for broadcasting receivers.

The seventh aspect of the invention resides in the DBS tuner for satellite broadcasting receivers having the above second feature, wherein the attenuating filter is provided in the power supply line inside the DBS tuner for broadcasting receivers.

The eighth aspect of the invention resides in the DBS tuner for satellite broadcasting receivers having the above first feature, wherein the attenuating filter is provided between the demodulating portion of the DBS tuner for broadcasting receivers and the attenuator.

The ninth aspect of the invention resides in the DBS tuner for satellite broadcasting receivers having the above second feature, wherein the attenuating filter is provided between the demodulating portion of the DBS tuner for broadcasting receivers and the attenuator.

The tenth aspect of the invention resides in the DBS tuner for satellite broadcasting receivers having the above

first feature, wherein the attenuating filter is provided in the transmission line for the locally generated signal from the local oscillator circuit portion to the PLL circuit portion in the DBS tuner for satellite broadcasting tuner.

Finally, the eleventh aspect of the invention resides in the DBS tuner for satellite broadcasting receivers having the second feature, wherein the attenuating filter is provided in the transmission line for the locally generated signal from the local oscillator circuit portion to the PLL circuit portion in the DBS tuner for satellite broadcasting tuner.

BRIEF DESCRIPTION OF THE DRAWINGS

Fig. 1 is a block diagram showing a circuit of a conventional DBS tuner for satellite broadcasting receivers;

Fig. 2 is a circuit diagram showing the configuration of a low-pass filter according to the prior art.

Fig. 3 is a circuit diagram showing a bypass capacitor according to the prior art;

Fig. 4 is a perspective view showing a RF signal line of a conventional DBS tuner for satellite broadcasting receivers;

Fig. 5 is a block diagram showing a circuit of a DBS tuner for satellite broadcasting receivers in accordance with an embodiment of the invention;

Fig. 6A is a perspective view showing a pattern model of an attenuating filter composed of a single microstrip line having an open-ended load terminal, in a DBS tuner for satellite broadcasting receivers in accordance with an embodiment of the invention;

Fig. 6B is a chart showing the relationship between the frequency and the input impedance Z_{in} in the configuration of Fig. 6A;

Fig. 7A is a perspective view showing a pattern model of an attenuating filter composed of a plurality of microstrip lines having open-ended load terminals in a DBS tuner for satellite broadcasting receivers in accordance with an embodiment of the invention;

Fig. 7B is a chart showing the relationship between the frequency and the input impedance Z_{in} in the configuration of Fig. 7A in which two microstrip lines different in length are provided;

Fig. 7C is a chart showing the relationship between the frequency and the input impedance Z_{in} in the configuration of Fig. 7A in which a plurality of microstrip lines different in length are provided;

Fig. 8 is a sectional view showing a printed circuit board;

Fig. 9 is a perspective view showing a microstrip line provided on a printed circuit board in accordance with an embodiment of the invention; and

Fig. 10 is a chart showing the relationship between the length L of the microstrip line provided on the printed circuit board in accordance with an embodiment of the invention and the input impedance Z_{in} with respect to the signal line.

DESCRIPTION OF THE PREFERRED EMBODIMENTS

Figs. 5 through 10 show embodiments of the invention. The present invention will be described in detail with reference to the embodiments shown.

Referring first to Figs. 8, 9 and 10, description will be made of the operational principle of the subject invention, i. e., a microstrip line having an open-ended load terminal. Fig. 8 is a sectional view of a printed circuit board; Fig. 9 is a pattern model on the actual board; and Fig. 10 is a chart showing the characteristics.

In Fig. 8, designated at 5 is a dielectric substrate for the printed circuit board. The hard printed circuit board (PWB) is about 0.5 to 1.5 mm in thickness (h). Reference numerals 2 and 4 are copper foil layers of about 18 to 35 m thick, coated on both sides of the substrate. The substrate is almost entirely covered on its lower side by copper foil layer 4 while the one on the upper side, copper foil layer 2 forms a microstrip line which is provided band like with a line width W_0 of about 0.2 to 2.0 mm.

Coated on the microstrip line is a solder resist. The effect of the solder resist is to protect the conductor from corrosion and prevent solder from adhering. The input impedance Z_{in} with respect to the signal line in the configuration of Fig. 9, is represented by the following formula:

$$Z_{in} = -j \times Z_0 \times \cot \beta L \quad (1)$$

where Z_0 is the characteristic impedance of microstrip line 2, β is a phase constant and L is the length of microstrip line.

Here, Z_{in} becomes equal to 0 ($Z_{in} = 0 (\Omega)$) for the signal having a frequency meeting the following equation, which is equivalent to an input terminal being grounded:

$$L = (2n + 1) \lambda_g / 4 \quad (n \text{ is an integer}) \quad (2)$$

where λ_g represents the wavelength of a signal in the transmission line length. The present invention, from this view point, provides a microstrip line serving as an attenuating filter (i.e., a trap circuitry) for the printed circuit board of a DBS tuner for satellite broadcasting receivers.

Now, detailed description will be made of the attenuating filter (trap circuitry) formed of a microstrip line which is provided in the RF line, having an open-ended load terminal. When a microstrip line has a shape shown in Fig.9, Wheeler's formula for determining the characteristic impedance Z_0 of the microstrip line is given as follows:

$$Z_0 = 42.4 / (\epsilon + 1)^{1/2} \times \ln(1 + (4 \times h / W)) \times (b + (b^2 + a \times \pi^2)^{1/2}) \quad (3)$$

where

$$W = W_0 + a \times \Delta W_0$$

$$\Delta W_0 = t / \pi (1 + \ln(4 / (t/h)^2 + (1 / (\pi \times (W_0/t + 1.1)))^2)^{1/2})$$

$$a = (1 + 1/\epsilon) / 2$$

$$b = (14 + 8/\epsilon) / 11 \times 4 \times h / W$$

ϵ : dielectric constant on the substrate

W_0 : microstrip line width

h : thickness of the dielectric substrate

t : microstrip line thickness

In a microstrip line, part of the electric field leaks out into the air. This can be considered to be equivalent to reducing the dielectric constant of the dielectric substrate. This effective dielectric constant ϵ_{eff} is given from the Wheeler's formula, as follows:

$$\epsilon_{\text{eff}} = \epsilon - (\epsilon - \epsilon_{\text{effo}}) / (1 + G(f_p)^2) \quad (4)$$

where

$$G = 0.6 + 0.009 \times Z_0 \quad (Z_0 : \Omega)$$

$$f_p = Z_0 / (0.80 \times \pi \times h) \quad (h : \text{mm})$$

$$\epsilon_{\text{effo}} = (Z_{00} / Z_0)^2$$

f : the frequency in use [GHz]

Z_{00} : the characteristic impedance when the dielectric substrate is removed.

These formulae (3) and (4) are cited from 'Design and packaging of high-frequency circuit' pp.26-27 (Yukihiko Miyamoto, published by Japan Broadcast Publishing Co., Ltd. the third edition, printed in 1989).

Further, the following relationship between the frequency and the wavelength holds:

$$\lambda_g = C / (f \times (\epsilon_{eff})^{1/2}) \quad (5)$$

$$C = 2.998 \times 10^{10} \text{ cm/sec}$$

(C = the velocity of light)

From the above, when, for instance, the third order harmonic range in the locally generated signal, i.e., the 5 GHz band, needs be damped, the dimensions is set so that the width of the microstrip line is 0.4 mm, the dielectric constant is set to be $\epsilon = 3.8$ (when the material of the printed circuit board is made of glass epoxy, for instance), the thickness t of the microstrip line is 0.018 mm (or 18 μ m) and the thickness h of the dielectric substrate is 1 mm. In this case, the length of the microstrip line $L = \lambda_g/4$ is calculated as $L \approx 9.2$ mm from the formulae (2), (3) and (4). If the second order harmonic range in the locally generated signal, i.e., the 3.2 GHz band is wanted to be damped, the length of the microstrip line is determined from the above coefficients, to be $L \approx 14.5$ mm.

Further, the length of microstrip line 2 is set so that $L = \lambda_g/4$ holds for the frequency to be attenuated. The line width W_0 of microstrip line 2 is related to the band width to be trapped, and it is possible to increase the band width, as the line width W_0 is increased. In formula (1), β (phase constant) is a function of the frequency, the rate of change in the value of Z_{in} is determined depending on the value Z_0 . Now, if the line width W_0 is increased, Z_0 will change, becoming smaller. Accordingly, the change of rate of Z_{in} for the frequency becomes smaller. Hence, a broadening of the band width can be achieved.

Fig.10 is a chart showing the relationship between the characteristic impedance Z_{in} with respect to the signal source side and the length L of microstrip line 2. From this chart it is understood: when $L = (2n+1)\lambda_g/4$, then $Z_{in} = 0$; and when $L = (2n+1)\lambda_g/2$, then $Z_{in} = \infty$ (infinity).

Figs.6A,6B and Figs.7A-7C show embodiments of the invention in which one or two microstrip lines each having an open-ended load terminal are provided based on the above theory. Fig.5 is a block diagram showing a DBS tuner for satellite broadcasting receivers to which the embodiment is applied.

In Fig.6A, a signal line 1 is formed with a single microstrip line 2 having an open-ended load terminal. The length of this microstrip line 2 is designed so that $L_1 = \lambda_g/4$ holds for a frequency f_1 to be attenuated.

Fig.6B is a graph showing the transmission characteristic of signal line 1, plotting the input impedance Z_{in} or the attenuated quantity vs. frequency along the horizontal axis. In the case of the input impedance Z_{in} , it represents the input impedance Z_{in} of a stub with respect to signal line 1.

In Fig.7A, two microstrip lines 2 and 3 having open-ended load terminals are designed and provided for the signal line to attenuate two frequencies f_1 and f_2 . In this case, the lengths are set so that $L_1 = \lambda_g/4$ and $L_2 = \lambda_g/4$ hold. In this case, in one embodiment, when $f_1 = 4.8$ GHz, then $L_1 = 9.2$ mm; and when $f_2 = 3.2$ GHz, then $L_2 = 14.5$ mm. The line width of signal line 1 is set at 0.4 mm; the line width W_0 of the microstrip lines is set at 0.4 mm; and the thickness t of the copper foil is 18 μ m.

Fig.7B is a graph showing the relationship between frequencies f_1 and f_2 vs. the input impedance Z_{in} or the attenuated quantity. Here, $L_1 > L_2$, $f_1 < f_2$. A plurality of microstrip lines different in length are provided. The lengths are set with $L_1 > L_2 > L_3 \dots > L_n$, and the frequencies to be attenuated becomes $f_1 < f_2 < f_3 < \dots < f_n$. When the values f_1, f_2, f_3, \dots are selected close to each other, it is possible to reduce the value of the input impedance Z_{in} (or increase the attenuated quantity) in a broader frequency band range. This is shown in Fig.7C.

In Fig.7B, a case comprising a plurality of microstrip lines different in length was described. It is also possible to provide a plurality of microstrip lines having almost the same length. This setup can increase the attenuating level for the frequency to be attenuated.

Fig.5 is a block diagram showing a circuit of a DBS tuner for satellite broadcasting receivers in accordance with an embodiment of the invention. The double line connecting different circuit portions represents the high-frequency signal line; the signal line represents the power line.

In Fig.5, the input signal of the 1 GHz band applied to an input terminal 31 is made to pass through a wide-band a RF circuit portion 32, an attenuator 33, a tracking filter 34 to be supplied to a mixer 35. The locally generated signal from a local oscillator circuit portion 36 is inputted to a PLL (phase-locked loop) 38 through a high-pass filter 37. PLL 38 operates so that the locally generated signal (1300 MHz to 2550 MHz) from local oscillator circuit portion 36 is phase-locked. The locally generated signal locked in phase is inputted to mixer 35 where it is converted into the intermediate frequency signal (IF signal). This IF signal is applied to an IF circuit portion 40 and inputted to a demodulating portion 41. The signal demodulated is inputted into an output terminal 48 through a signal output line 47. A reference numeral 42 designates a power input terminal which is connected to RF circuit portion 32, mixer 35, PLL 38, local oscillator circuit portion 36, IF circuit portion 40 and demodulating portion 41. The frequency of the IF signal output in this case is 402.78 MHz.

Here, the distinction of the invention shown in Fig.5 from the configuration of Fig.1 resides in that one or more

microstrip lines with an open-ended load terminal are provided in the high-frequency signal line. In Fig. 3, as an example, attenuating filters (trap circuitry) 43, 44, 45 and the like made up of microstrip lines with open-ended load terminals are provided between attenuator 33 and tracking filter 34, between local oscillator circuit 36 and bypass filter 37, and between demodulating portion 41 and attenuator 33, and the like. Attenuating filter (trap circuitry) 45 is typically provided in RFAGC line 39.

Another attenuating filter (trap circuitry) 46 made up of a microstrip line with an open-ended load terminal is provided between interconnections from power input terminal 42 to RF circuit portion 32, mixer 35, PLL 38, local oscillator circuit portion 36, IF circuit portion 40 and demodulating portion 41.

Here, the frequency of the fundamental wave of the locally generated signal is from 1300 MHz to 2550 MHz. The frequency of its second order harmonic falls within $(1300 \text{ MHz to } 2550 \text{ MHz}) \times 2$ and the frequency of its third order harmonic falls within $(1300 \text{ MHz to } 2550 \text{ MHz}) \times 3$.

The frequency of the fundamental wave of the VCO oscillating signal is 402.78 MHz. The frequency of its second order harmonic is $402.78 \text{ MHz} \times 2$, and the frequency of its third order harmonic is $402.78 \text{ MHz} \times 3$.

Trap circuitry 43 is so designed that the microstrip line mainly damps the second and third order harmonics of the fundamental wave ranging from 1300 to 2550 MHz. Trap circuit 44 is so designed that it mainly damps the second and third order harmonics of the fundamental wave of 402.78 MHz. Trap circuitry 45 is so designed that it mainly damps the second and third order harmonics of the fundamental wave ranging from 1300 to 2550 MHz. Trap circuitry 46 provided for the power input line is designed so as to target the fundamental frequency ranging from 1300 to 2550 MHz and the fundamental wave of 402.78 MHz of the VCO oscillating signal. Trap circuitry 46 may optionally target the second and third order harmonics of these waves.

Although in the above example, an attenuating filter (trap circuitry) was provided in the RF signal line, it may be provided in any location from the input terminal to the local oscillator circuit. Although in the above example, the width of the microstrip line was set at 0.4 mm, the width should not be limited to this but can be changed as appropriate. Although in the above example, the length of the microstrip line was set so that $L = \lambda/4$ for the frequency to be damped, the length may be set equal to $(2n+1)\lambda/4$ (n is an integer). In this embodiment, the intermediate frequency was set at 402.78 MHz, however, it can be set at a frequency of 479.5 MHz. In this case, apparently the fundamental wave of the locally generated signal ranges from 1379.5 MHz to 2629.5 MHz; the fundamental wave of the VCO oscillating signal becomes equal to 479.5 MHz. In this setup, the RF frequencies generating beats fall at 959 MHz, 1438.5 MHz and 1909 MHz. The RF frequency was described to be 900 to 2150 MHz, but it should not be limited to this range. Further, the frequencies to be damped were described up to the third order harmonic component, but they are not limited to this.

Thus, in accordance with the first aspect of the invention, in the DBS tuner for satellite broadcasting receivers, a microstrip line having an open-ended load terminal is provided in the RF signal line or the power supply line so that it projects from the line forming an attenuating filter (trap circuitry). Thus, it becomes possible to attenuate signals of high frequency ranges, which were hard to handle, by simply changing the circuit pattern during the manufacture of the DBS tuner. Consequently, it is possible to suppress the interference of the DBS tuner with other DBS tuners connected with the same cable and other appliances, to prevent malfunction of channel section in the PLL from occurring, to reduce unwanted radiation from the appliance body incorporating the DBS tuner, and to suppress generation of beats on the display screen when the RF frequency received is close to the frequency of a higher harmonic of the VCO oscillating signal. Since this circuit pattern can be formed on the printed circuit board, it is possible to achieve this without any increase in cost.

In accordance with the second feature of the invention, the attenuating filter is configured with a plurality of microstrip lines different in length having a plurality of open-ended load terminals. This configuration enables effective attenuation of different frequencies.

In accordance with the third aspect of the invention, the attenuating filter is configured so that a GND pattern is formed almost entirely on the dielectric substrate on the side opposite to the surface where the microstrip lines are formed. This configuration makes the distribution of the electric field formed between the microstrip lines and GND pattern uniform, thus simplifying the design of the attenuating filter.

In accordance with the fourth and fifth aspects of the invention, the aforementioned attenuating filter is provided in the RF line which connects the input terminal to the DBS tuner for broadcasting receivers with the local oscillator circuit portion. Therefore, it is possible to prevent the leakage of the locally generated signal through the input terminal. Accordingly, the tuner of the invention will not interfere with other DBS tuners which are connected through the same cable as well as other appliances.

In accordance with the sixth and seventh aspects of the invention, the aforementioned attenuating filter is provided in the power supply line inside the DBS tuner for broadcasting receivers. Therefore, it is possible to prevent leakage of the locally generated signal through the power terminal. Accordingly, it is possible to eliminate unwanted radiation from the appliance body almost to nothing.

In accordance with the eighth and ninth aspects of the invention, the aforementioned attenuating filter is provided

between the demodulating portion of the DBS tuner for broadcasting receivers and the attenuator (or in the RFAGC line), it is possible to prevent entrance of the higher harmonic components from the VCO oscillating signal in the demodulating circuit portion into the RFAGC line. This makes it possible to reduce generation of beats on the display screen when the RF frequency received is close to the frequency of a higher harmonic of the VCO oscillating signal.

In accordance with the tenth and eleventh aspects of the invention, the attenuating filter is provided in the transmission line for the locally generated signal from the local oscillator circuit portion to the PLL circuit portion in the DBS tuner for satellite broadcasting tuners. This configuration prevents entrance of the second order and third order harmonic components of the locally generated signal into the PLL circuit portion. Accordingly, it is possible to prevent malfunction of channel section in the PLL.

Claims

1. A DBS tuner for satellite broadcasting receivers, comprising an attenuating filter composed of a microstrip line having an open-ended load terminal which projects from the RF signal line or the power supply line.
2. A DBS tuner for satellite broadcasting receivers according to claim 1, wherein the attenuating filter is configured with a plurality of microstrip lines different in length having a plurality of open-ended load terminals.
3. A DBS tuner for satellite broadcasting receivers according to claim 1, wherein the attenuating filter is configured so that a GND pattern is formed almost entirely on the dielectric substrate on the side opposite to the surface where the microstrip lines are formed.
4. A DBS tuner for satellite broadcasting receivers according to claim 1, wherein the attenuating filter is provided in the RF line which connects the input terminal to the DBS tuner for broadcasting receivers with the local oscillator circuit portion.
5. A DBS tuner for satellite broadcasting receivers according to claim 2, wherein the attenuating filter is provided in the RF line which connects the input terminal to the DBS tuner for broadcasting receivers with the local oscillator circuit portion.
6. A DBS tuner for satellite broadcasting receivers according to claim 1, wherein the attenuating filter is provided in the power supply line inside the DBS tuner for broadcasting receivers.
7. A DBS tuner for satellite broadcasting receivers according to claim 2, wherein the attenuating filter is provided in the power supply line inside the DBS tuner for broadcasting receivers.
8. A DBS tuner for satellite broadcasting receivers according to claim 1, wherein the attenuating filter is provided between the demodulating portion of the DBS tuner for broadcasting receivers and the attenuator.
9. A DBS tuner for satellite broadcasting receivers according to claim 2, wherein the attenuating filter is provided between the demodulating portion of the DBS tuner for broadcasting receivers and the attenuator.
10. A DBS tuner for satellite broadcasting receivers according to claim 1, wherein the attenuating filter is provided in the transmission line for the locally generated signal from the local oscillator circuit portion to the PLL circuit portion in the DBS tuner for satellite broadcasting tuner.
11. A DBS tuner for satellite broadcasting receivers according to claim 2, wherein the attenuating filter is provided in the transmission line for the locally generated signal from the local oscillator circuit portion to the PLL circuit portion in the DBS tuner for satellite broadcasting tuner.
12. A tuner for a receiver, including an RF signal line, a power supply line and an attenuating filter composed of an open ended microstrip line which projects from the RF signal line or the power supply line.

FIG. 1 PRIOR ART

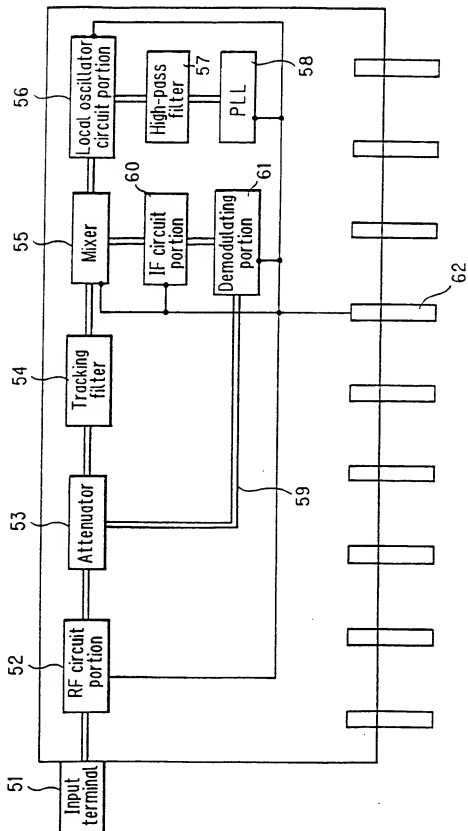


FIG 2 PRIOR ART

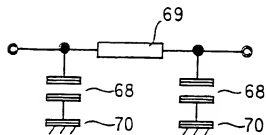


FIG.3 PRIOR ART

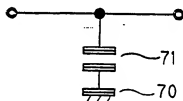


FIG.4 PRIOR ART

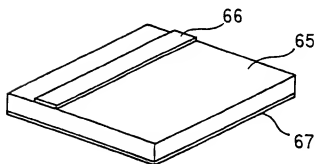


FIG. 5

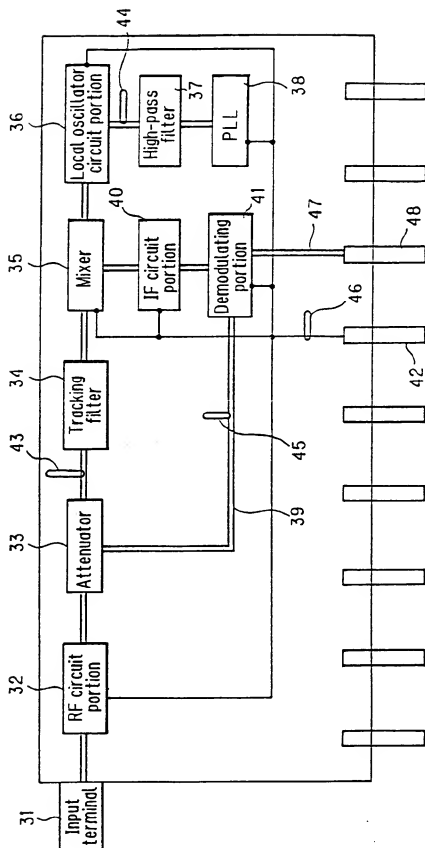


FIG. 6A

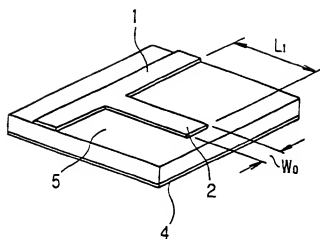


FIG. 6B

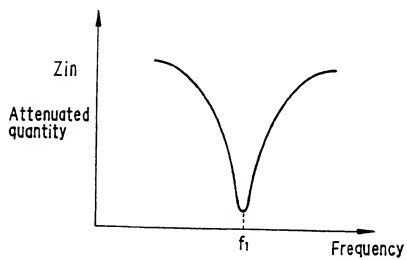


FIG. 7A

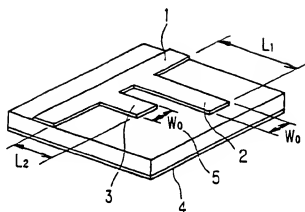


FIG. 7B

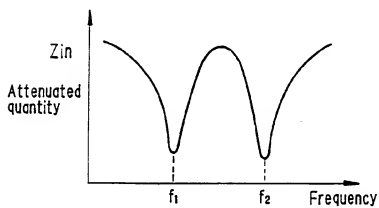


FIG. 7C

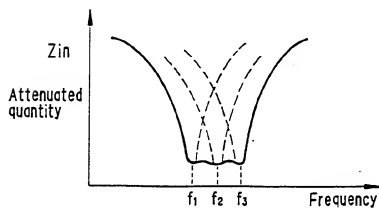


FIG. 8

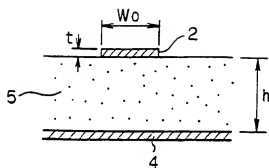


FIG. 9

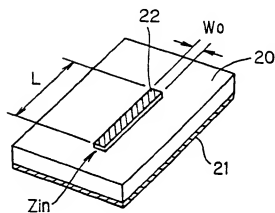
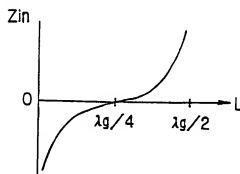


FIG. 10



(19)



Europäisches Patentamt
European Patent Office
Office européen des brevets



(11)

EP 0 803 927 A3

(12)

EUROPEAN PATENT APPLICATION

(88) Date of publication A3:
14.07.1999 Bulletin 1999/28

(51) Int. Cl. 6: H01P 1/00, H03D 9/06,
H01P 1/203

(43) Date of publication A2:
29.10.1997 Bulletin 1997/44

(21) Application number: 97302840.0

(22) Date of filing: 25.04.1997

(84) Designated Contracting States:
DE FI FR GB

(72) Inventor: Wada, Yasuhiro
Takatsuki-shi, Osaka (JP)

(30) Priority: 26.04.1996 JP 10724396

(74) Representative: Brown, Kenneth Richard et al
R.G.C. Jenkins & Co.
26 Caxton Street
London SW1H 0RJ (GB)

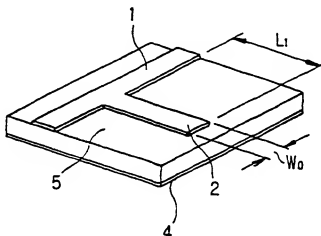
(71) Applicant: SHARP KABUSHIKI KAISHA
Osaka-shi, Osaka-fu 545-0013 (JP)

(54) Attenuating filter for a DBS tuner for satellite broadcasting receivers

(57) A DBS tuner for satellite broadcasting receivers, includes an attenuating filter (trap circuitry) com-

posed of a microstrip line having an open-ended load terminal which projects from the RF signal line or the power supply line.

FIG. 6A



EP 0 803 927 A3



European Patent
Office

EUROPEAN SEARCH REPORT

Application Number
EP 97 30 2840

DOCUMENTS CONSIDERED TO BE RELEVANT			
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int.Cl.8)
X	EP 0 317 642 A (MATSUSHITA ELECTRIC IND CO LTD) 31 May 1989 * figure 4 *	1-6,12	H01P1/00 H03D9/06 H01P1/203
X	US 5 202 651 A (YOSHIMASU TOSHIHIKO) 13 April 1993	1,3	
Y	* column 1, line 1 - column 3, line 16; figures 1-4 *	2	
Y	PATENT ABSTRACTS OF JAPAN vol. 007, no. 076 (E-167), 30 March 1983 -& JP 58 005001 A (MATSUSHITA DENKI SANGYO KK), 12 January 1983	2	
A	* abstract; figures 6-8 *	5,7,9,11	
			TECHNICAL FIELDS SEARCHED (Int.Cl.8)
			H03D H01P
The present search report has been drawn up for all claims			
Place of search THE HAGUE		Date of completion of the search 20 May 1999	Examiner Peeters, M
CATEGORY OF CITED DOCUMENTS			
X: particularly relevant if taken alone Y: particularly relevant if combined with another document of the same category A: technological background O: non-written disclosures P: intermediate document		T: theory or principle underlying the invention E: earlier patent document, but published on, or after the filing date D: document cited in the application L: document cited for other reasons A: member of the same patent family, corresponding document	

EP FORM 1503 01 92 (PAC/CI)

**ANNEX TO THE EUROPEAN SEARCH REPORT
ON EUROPEAN PATENT APPLICATION NO.**

EP 97 30 2840

This annex lists the patent family members relating to the patent documents cited in the above-mentioned European search report. The members are as contained in the European Patent Office EDP file on
The European Patent Office is in no way liable for these particulars which are merely given for the purpose of information

20-05-1999

Patent document cited in search report	Publication date	Patent family member(s)	Publication date
EP 0317642 A	31-05-1989	JP 2563338 B	11-12-1996
		JP 63302608 A	09-12-1988
		DE 3855823 D	17-04-1997
		DE 3855823 T	18-09-1997
		DK 45089 A	30-03-1989
		WO 8810024 A	15-12-1988
		US 4996718 A	26-02-1991
US 5202651 A	13-04-1993	JP 4225601 A	14-08-1992

EPO FORM P443

For more details about this annex : see Official Journal of the European Patent Office, No. 12/82